







**SN74HCT08** 

SCLS063G - NOVEMBER 1988 - REVISED AUGUST 2024

## SN74HCT08 Quadruple 2-Input Positive-AND Gates

### **1** Features

Texas

INSTRUMENTS

- Operating voltage range of 4.5V to 5.5V •
- Outputs can drive up to 10 LSTTL loads •
- Low power consumption, 20µA max I<sub>CC</sub>
- Typical t<sub>pd</sub> = 13ns
- ±4mA output drive at 5V
- Low input current of 1µA max
- Inputs are TTL-voltage compatible

## **2** Description

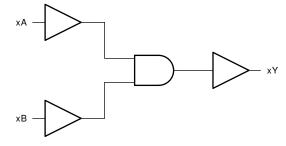
These devices contain four independent 2-input AND gates. They perform the Boolean function  $Y = A \cdot B$  in positive logic.

Package	Information	
	(0)	

	•		
PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>	BODY SIZE <sup>(2)</sup>
	D (SOIC, 14)	8.65mm × 6mm	8.65mm × 3.9mm
	DB (SSOP, 14)	6.20mm × 7.8mm	6.20mm × 5.30 mm
SN74HCT08	N (PDIP, 14)	19.30mm × 9.4mm	19.30mm × 6.35mm
	NS (SO, 4)	10.20mm × 7.8mm	10.20mm × 5.30mm
	PW (TSSOP, 14)	5.00mm × 6.4mm	5.00mm × 4.40mm

(1) For more information, see Mechanical, Packaging, and Orderable Information.

(2) The body size (length × width) is a nominal value and does not include pins.



**Functional Block Diagram** 





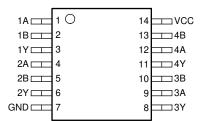
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## **3 Pin Configuration and Functions**



#### D, DB, J, N, NS, PW or W Package 14-Pin SOIC, SSOP, PDIP, SO or TSSOP Top View

#### Table 3-1. Pin Functions

PIN		TYPE <sup>(1)</sup>	DESCRIPTION				
NAME	NO.		DEGCRIPTION				
1A	1	Input	Channel 1, Input A				
1B	2	Input	Channel 1, Input B				
1Y	3	Output	Channel 1, Output Y				
2A	4	Input	Channel 2, Input A				
2B	5	Input	Channel 2, Input B				
2Y	6	Output	Channel 2, Output Y				
GND	7	_	Ground				
3Y	8	Output	Channel 3, Output Y				
3A	9	Input	Channel 3, Input A				
3B	10	Input	Channel 3, Input B				
4Y	11	Output	Channel 4, Output Y				
4A	12	Input	Channel 4, Input A				
4B	13	Input	Channel 4, Input B				
V <sub>CC</sub>	14	_	Positive Supply				

(1) Signal Types: I = Input, O = Output, I/O = Input or Output



## **4** Specifications

### 4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	$(V_{I} < 0 \text{ or } V_{I} > V_{CC})$		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20	mA
I <sub>O</sub>	Continuous output current	$(V_O = 0 \text{ to } V_{CC})$		±25	mA
V <sub>CC</sub> or GND	ND Continuous current through			±50	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### 4.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			SN	SN74HCT08		
			MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage		4.5	5	5.5	V
VIH	High-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2			V
VIL	Low-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V			0.8	V
VI	Input voltage		0		$V_{CC}$	V
Vo	Output voltage		0		$V_{CC}$	V
Δt/Δv	Input transition rise/fall time				500	ns
T <sub>A</sub>	Operating free-air temperature		- 40		85	°C

 All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report Implications of Slow or Floating SMOS Inputs, literature number SCBA004.

#### 4.3 Thermal Information

		D (SOIC)	DB (SSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	
THERMAL	METRIC	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	UNIT
R <sub>θJA</sub>	Junction-to-ambient thermal resistance <sup>(1)</sup>	138.7	114.8	103.8	129.3	157.6	°C/W
R <sub>0JC (top)</sub>	Junction-to-case (top) thermal resistance	93.8	60	91.6	85.7	84.1	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	94.7	63.8	83.5	89.9	100.8	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	49.1	19.7	71.1	48.2	27.5	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	94.3	63.1	83.4	89.4	100.2	°C/W
R <sub>0JC (bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.



### **4.4 Electrical Characteristics**

PARAMETER		TEST CONDITIONS <sup>(1)</sup> Vcc (V)		T <sub>A</sub> = 25°C			SN74H0	UNIT	
	PARAMIETER		V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	UNIT
V <sub>OH</sub>	High-level output voltage	I <sub>OH</sub> = –20 μA	4.5	4.4	4.499		4.4		V
∙он		I <sub>OH</sub> = -4 mA	4.5	3.98	4.3		3.84		v
V	Low-level output voltage	I <sub>OL</sub> = 20 μA	4.5		0.001	0.1		0.1	V
V <sub>OL</sub>	Low-level output voltage	I <sub>OL</sub> = 4 mA			0.17	0.26		0.33	v
I <sub>I</sub>	Input hold current	V <sub>I</sub> = V <sub>CC</sub> or 0	5.5		±0.1	±100		±1000	nA
I <sub>CC</sub>	Supply current	$V_{I} = V_{CC} \text{ or } 0. I_{O} = 0$	5.5			2		20	μA
ΔI <sub>CC</sub> <sup>(2)</sup>	Supply-current change	One input at 0.5V or 2.4 V, Other inputs at 0 or $V_{CC}$	5.5		1.4	2.4		2.9	mA
Ci	Input capacitance		4.5 to 5.5		3	10		10	pF

(1) V<sub>I</sub> = V<sub>IH</sub> or V<sub>IL</sub>, unless otherwise noted.
 (2) This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V<sub>CC</sub>.

### **4.5 Switching Characteristics**

C<sub>L</sub> = 50 pF. See Parameter Measurement Information

	PARAMETER	FROM (INPUT) TO (OUTPUT)			T <sub>A</sub> = 25°C	:	SN74HCT08		
	PARAMETER			V <sub>CC</sub> (V)	MIN TYP	MAX	MIN MAX		
t .	Propagation delay	A or B	~	4.5	15	24	30	ns	
Lpd	5.5	AUB		AOID	13	22	27	115	
t	t, Transition time		Transition time	~	4.5	9	15	19	ns
ч			I	5.5	8	14	17	115	

### **4.6 Operating Characteristics**

T<sub>A</sub> = 25°C

		Test Conditions	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance per gate	No load	20	pF

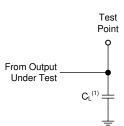


### **5** Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1MHz, Z<sub>O</sub> = 50 $\Omega$ , t<sub>t</sub> < 6ns.

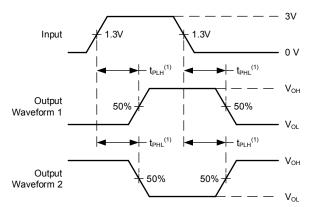
For clock inputs,  $f_{max}$  is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



(1) C<sub>L</sub> includes probe and test-fixture capacitance.

#### Figure 5-1. Load Circuit for Push-Pull Outputs



(1) The greater between  $t_{\mathsf{PLH}}$  and  $t_{\mathsf{PHL}}$  is the same as  $t_{\mathsf{pd}}.$ 

Figure 5-2. Voltage Waveforms, Propagation Delays for TTL-Compatible Inputs



## 6 Detailed Description

### 6.1 Overview

This device contains four independent 2-input AND Gates. Each gate performs the Boolean function  $Y = A \bullet B$  in positive logic.

#### 6.2 Functional Block Diagram

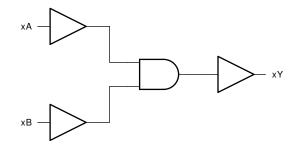


Figure 6-1. Functional Block Diagram

### 6.3 Device Functional Modes

Table 6-1 lists the functional modes of the SN74HCT08.

INPU	ITS <sup>(1)</sup>	OUTPUT				
Α	В	Y				
Н	Н	Н				
L	x	L				
x	L	L				

### Table 6-1. Function Table

 H = High Voltage Level, L = Low Voltage Level, X = Don't Care



### 7 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 7.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

### 7.2 Layout

#### 7.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.

#### 7.2.2 Layout Example

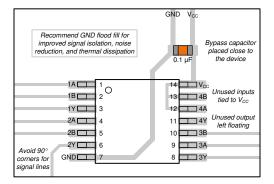


Figure 7-1. Example Layout for the SN74HCT08



### 8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

#### 8.1 Documentation Support

#### 8.1.1 Related Documentation

#### 8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 8.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 8.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 8.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

#### 9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision F (October 2022) to Revision G (August 2024)	Page
•	Added package size to Package Information table	1
•	Deleted references to preview-only GPN throughout data sheet	1
•	Added Pin Functions table	<mark>3</mark>
•	Updated R0JA values: N = 67 to 103.8, NS = 93.3 to 129.3, PW = 159.8 to 157.6; Updated N, NS, and I neckaras for P0 IC (tern) P0 ID. III IT III ID and P0 IC (tert) all values in $^{\circ}C(M)$	
•	packages for RθJC(top), RθJB, ΨJT, ΨJB, and RθJC(bot), all values in °C/W Added <i>Application and Implementation</i> section	

#### Changes from Revision E (February 2022) to Revision F (October 2022) Page



## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74HCT08D	OBSOLETE	SOIC	D	14		TBD	(6) Call TI	Call TI	-40 to 85	HCT08	
SN74HCT08DBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT08	Samples
SN74HCT08DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	HCT08	Samples
SN74HCT08DRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT08	Samples
SN74HCT08DRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT08	Samples
SN74HCT08N	ACTIVE	PDIP	Ν	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HCT08N	Samples
SN74HCT08NE4	ACTIVE	PDIP	Ν	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HCT08N	Samples
SN74HCT08NSR	ACTIVE	SOP	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT08	Samples
SN74HCT08PW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85	HT08	
SN74HCT08PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	HT08	Samples
SN74HCT08PWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT08	Samples
SN74HCT08PWT	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85	HT08	

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



## PACKAGE OPTION ADDENDUM

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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NSTRUMENTS

### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HCT08DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74HCT08DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT08DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT08DRE4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT08DRE4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT08DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT08DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT08NSR	SOP	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74HCT08PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HCT08PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HCT08PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HCT08PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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# PACKAGE MATERIALS INFORMATION

7-Dec-2024



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HCT08DBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74HCT08DR	SOIC	D	14	2500	356.0	356.0	35.0
SN74HCT08DR	SOIC	D	14	2500	356.0	356.0	35.0
SN74HCT08DRE4	SOIC	D	14	2500	356.0	356.0	35.0
SN74HCT08DRE4	SOIC	D	14	2500	356.0	356.0	35.0
SN74HCT08DRG4	SOIC	D	14	2500	356.0	356.0	35.0
SN74HCT08DRG4	SOIC	D	14	2500	356.0	356.0	35.0
SN74HCT08NSR	SOP	NS	14	2000	356.0	356.0	35.0
SN74HCT08PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74HCT08PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74HCT08PWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74HCT08PWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0

## TEXAS INSTRUMENTS

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7-Dec-2024

## TUBE



## - B - Alignment groove width

#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74HCT08N	N	PDIP	14	25	506	13.97	11230	4.32
SN74HCT08N	N	PDIP	14	25	506	13.97	11230	4.32
SN74HCT08NE4	N	PDIP	14	25	506	13.97	11230	4.32
SN74HCT08NE4	N	PDIP	14	25	506	13.97	11230	4.32

# **D0014A**



# **PACKAGE OUTLINE**

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



# D0014A

# **EXAMPLE BOARD LAYOUT**

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# D0014A

# **EXAMPLE STENCIL DESIGN**

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## MECHANICAL DATA

### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# **DB0014A**



# **PACKAGE OUTLINE**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not

- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-150.



# DB0014A

# **EXAMPLE BOARD LAYOUT**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# DB0014A

# **EXAMPLE STENCIL DESIGN**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



## N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



# **PW0014A**



# **PACKAGE OUTLINE**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



## PW0014A

# **EXAMPLE BOARD LAYOUT**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## PW0014A

# **EXAMPLE STENCIL DESIGN**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



<sup>8.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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